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Structural and thermodynamic similarities of phases in the Li-Tt (Tt = Si, Ge) systems: redetermination of the lithium-rich side of the Li-Ge phase diagram and crystal structures of $Li_{17}Si_{4.0-x}Ge_x$ for x = 2.3, 3.1, 3.5, and 4 as well as $Li_{4.1}Ge^{+}$

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A reinvestigation of the lithium-rich section of the Li-Ge phase diagram reveals the existence of two new phases, $Li_{17}Ge_4$ and $Li_{4.10}Ge$ ($Li_{16.38}Ge_4$). Their structures are determined by X-ray diffraction experiments of large single crystals obtained from equilibrated melts with compositions $Li_{95}Ge_5$ and $Li_{85}Ge_{15}$. Excess melt is subsequently removed through isothermal centrifugation at 400 °C and 530 °C, respectively. Li₁₇Ge₄ crystallizes in the space group $F\bar{4}3m$ (a = 18.8521(3) Å, V = 6700.1(2) Å³, Z = 20, T = 298 K) and Li_{4.10}Ge (Li_{16.38}Ge₄) in Cmcm (a = 4.5511(2) Å, b = 22.0862(7) Å, c = 13.2751(4) Å, V = 1334.37(8) Å³, Z = 16, T = 123 K). Both phases are isotypic with their Si counterparts and are further representative of the $Li_{17}Pb_4$ and $Li_{4.11}Si$ structure types. Additionally, the solid solutions $Li_{17}Si_{4-x}Ge_x$ follows Vegard's law. A comparison of the GeLin coordination polyhedra shows that isolated Ge atoms are 13- and 14-coordinated in Li₁₇Ge₄, whereas in Li_{16.38}Ge₄ the Ge atoms possess coordination numbers 12 and 13. Regarding the thermodynamic stability, Li_{16.38}Ge₄ is assigned a high-temperature phase existing between \sim 400 °C and 627 °C, whereas Li₁₇Ge₄ decomposes peritectically at 520-522 °C. Additionally, the decomposition of Li_{16.38}Ge₄ below ~400 °C was found to be very sluggish. These findings are manifested by differential scanning calorimetry, long-term annealing experiments and the results from melt equilibration experiments. Interestingly, the thermodynamic properties of the lithium-rich tetrelides Li₁₇Tt₄ and $\text{Li}_{4.1}\text{Tt}$ ($\text{Li}_{16.4}\text{Tt}_4$) are very similar (Tt = Si, Ge). Besides $\text{Li}_{15}\text{Tt}_4$, $\text{Li}_{14}\text{Tt}_6$, $\text{Li}_{12}\text{Tt}_7$, and LiTt, the title compounds are further examples of isotypic tetrelides in the systems Li-Tt.

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Introduction

In the last decade, the demand for high capacity lithium-ion batteries (LIBs) decisively influenced numerous fields of

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† Electronic supplementary information (ESI) available: Crystallographic data, refinement results, fractional atomic coordinates, and isotropic equivalent atomic displacement parameters for $\mathrm{Li_{17}Si_{4-x}Ge_x}$ [x=2.30(2),~3.08(4),~3.53(3)] (Table S1–4), comparison of experimental and computational relaxed fractional atomic coordinates for both $\mathrm{Li_{21}Si_5}$ and $\mathrm{Li_{17}Si_4}$ (Table S5), experimental fractional atomic coordinates for $\mathrm{Li_{17}Si_4}$, $\mathrm{Li_{17}Ge_4}$, $\mathrm{Li_{17-e}}$ Zn_eGe₄, and $\mathrm{Li_{16.95}Ge_4}$ (Table S6), comparison of experimental fractional atomic coordinates for $\mathrm{Li_{16.95}Ge_4}$ and computational relaxed ones for $\mathrm{Li_{21}Si_5}$ (Table S7), PXRD patterns of " $\mathrm{Li_{16}Ge_4}$ " samples annealed at various temperatures (Fig. S1), Rietveld refinement results for $\mathrm{Li_{17}Si_{4-x}Ge_x}$ (x=0,2.30(2),3.08(4),3.53(3),4) (Fig. S2). See DOI: 10.1039/c4dt00743c

research; in particular, the chemistry of group 14 elements (tetrel = Tt) plays an important role in the development of more efficient anode materials. Since Si theoretically offers a specific capacity of 3579 mA h g⁻¹ (based on the formation of Li₁₅Si₄) and thus massively exceeds the capacity of the commonly used graphite anode (372 mA h g^{-1} , LiC₆), 1,2 research on Li-Si materials has been in focus for many years. As the high capacity of Si is associated with several problems such as a large volume expansion of up to 300% upon lithiation accompanied by contact loss of electrodes and poor cycle life, a large number of these studies target these issues.³ Further, Li-Si phases predominantly occur amorphously during charging and discharging, and only at low discharge voltages, crystalline Li₁₅Si₄ is observed. 1,2,4,5 However, the processes in working LIBs can be nicely monitored by in situ/ex situ NMR investigations. 6,7 Moreover, a fundamental understanding of thermodynamic properties and an unambiguous structural characterization of Li-Si phases are of considerable impor-

tance. Just recently, we reported on detailed investigations on lithium-rich silicides, including the metastable phase Li₁₅Si₄,8 Li₁₇Si₄⁹ and the high-temperature phase Li_{4.11}Si (Li_{16.42}Si₄). ¹⁰ Further examples are given in ref. 11-17.

The heavier tetrel element Ge has received less attention regarding its use as an anode material due to its low natural abundance connected with a lower theoretical specific capacity compared to silicon (1564 mA h g⁻¹ vs. 4056 mA h g⁻¹, based on the formation of Li_{16.95}Ge₄¹⁸ and Li₁₇Si₄, respectively). However, the diffusivity of lithium in Ge is approximately 400 times larger than in Si at room temperature, 19,20 which intrinsically puts germanium to the foreground. Since some Si analogues are not known we put emphasis on the structural variety of lithium germanides and their thermodynamic relation.

Li-Ge phases were first postulated in the 1950s and 1960s (Li₃Ge, Li₄Ge, LiGe), ²¹⁻²³ fueling numerous investigations in this field later on. Before 2001, the ascertained Li-Ge representatives included $\mathrm{Li_{21}Ge_5}^{24}$ (formerly described as $\mathrm{Li_{20}Ge_5}^{25,26}$ and $\mathrm{Li_{22}Ge_5}^{27,28}$), $\mathrm{Li_{15}Ge_4}^{28,29}$ $\mathrm{Li_{13}Ge_4}^{30}$ (formerly reported as Li₇Ge₂³¹), Li₁₄Ge₆, ^{25,26} Li₉Ge₄, ³² Li₁₂Ge₇, ^{25,26,33} LiGe (space group $I4_1/a$, ambient pressure), 22,34 LiGe (space group $I4_1/amd$, high pressure), 35 and Li₇Ge₁₂. 26,36 A previously described phase Li₁₁Ge₆³⁷ could not be reproduced in the course of the redetermination of the Li-Ge phase diagram by Grüttner, 25 and due to the "striking similarity" to Li₈MgSi₆, 38 it might have been ternary Li₈MgGe₆. Until then, solely Li₂₁Tt₅, Li₁₄Tt₆, Li₁₂Tt₇, and LiTt (LiSi³⁹ is obtainable from high-pressure synthesis) were known for both Si and Ge. We note that Li₁₃Si₄ and Li₁₃Ge₄ are not isotypic and crystallize with their own structure types. In the following years new Li-Tt phases were found and others were revised, e.g. a hexagonal high-pressure form of LiGe (space group P63/mmc),40 metastable Li₁₅Si₄1,2 being isotypic with the congruently melting phase Li₁₅Ge₄²⁵ $(Li_{15}Tt_4)$, $Li_{\sim 17}Ge_4$ $(Li_{21+3/16}Si_5 = Li_{16.95}Ge_4)^{18}$ revised from Li₂₁Ge₅, and the revision of the Li₇Ge₁₂ structure. ⁴¹ The synthesis of solid solutions Li₁₅Si_{4-x}Ge_x by mechanical ballmilling was also reported. 42 An experimental determination of the Li-Ge phase diagram involving most of the aforementioned phases is given by Grüttner in his dissertation.²⁵

We recently reported on the single crystal structures and thermodynamic properties of Li₁₇Si₄,⁹ the high-temperature phase Li_{4.11}Si (Li_{16.42}Si₄),¹⁰ and metastable Li₁₅Si₄.⁸ The Li-Si phase diagram was revised accordingly. Consequently, we extended our studies on the Li-Ge system. Herein, we present the single crystal X-ray structure determination of Li₁₇Ge₄ and Li_{4.10}Ge which crystallize isotypically with their Si counterparts. Earlier structure reports on Li~17Ge4 (Li21+3/16Si5 = Li_{16.95}Ge₄)¹⁸ involving partially occupied Li sites could not be confirmed. Solid solutions of the isotypic phases Li₁₇Si₄ and Li₁₇Ge₄ follow Vegard's law. 43 Due to clarity and a better comparability, the phase Li_{4.10}Ge is referred to as Li_{16.38}Ge₄. Furthermore, the lithium-rich section of the Li-Ge phase diagram (Li concentrations >79 at%) is reinvestigated by differential scanning calorimetry and long-term annealing experiments, manifesting Li_{16.38}Ge₄ as a high-temperature phase which possesses a very sluggish decomposition behavior below ~400 °C. Li₁₇Ge₄ is peritectically formed at 520-522 °C from cooling an according melt.

Results and discussion

Single crystal X-ray structure determination of Li₁₇Ge₄ and Li_{16.38}Ge₄

Large single crystals of Li₁₇Ge₄ and Li_{16,38}Ge₄ were grown in Li-Ge melts Li₉₅Ge₅ and Li₈₅Ge₁₅ at 400 °C and 530 °C, respectively. For Li_{16,38}Ge₄, bar-shaped crystals with a size of up to $0.6 \times 0.25 \times 0.25$ cm³ could be obtained. A representative specimen is depicted in Fig. 1. Generally, crystals of Li₁₇Ge₄ grew much smaller in a block-like shape with diameters of $0.1 \times 0.1 \times 0.1$ cm³. Those crystals allowed acquisition of high quality single crystal X-ray diffraction data.

The phase $Li_{17}Ge_4$ crystallizes in the space group $F\bar{4}3m$ with $a = 18.8521(3) \text{ Å} (V = 6700.1(2) \text{ Å}^3)$ and Z = 20. The asymmetric unit consists of 13 Li and four Ge atoms each being located on a special position (Table 1). As already reported for Li₁₇Si₄, $\text{Li}_{17}\text{Sn}_4$, and $\text{Li}_{17}\text{Pb}_4$, 9,18,44 the Wyckoff position 4a with symmetry $\bar{4}3m$ was found to be fully occupied. We note that the refinement of occupancy factors did not indicate significantly large deviations from full occupancy and thus they were regarded as being fully occupied. Accordingly, the cubic unit cell of Li₁₇Ge₄ contains 340 Li and 80 Ge atoms (cF420). Further, atomic displacement parameters were refined anisotropically with meaningful results for all atoms, revealing excellent reliability factors of $R_1 = 0.022$ and $wR_2 = 0.038$ (all data) for the final model (Table 6). The structure of Li₁₇Ge₄ is isotypic with Li₁₇Si₄, Li₁₇Sn₄, and Li₁₇Pb₄. ^{9,18,44}

 $Li_{16.38(2)}Ge_4$ crystallizes in the space group *Cmcm* with a =4.5511(2) Å, b = 22.0862(7) Å, c = 13.2751(4) Å (V = 1334.37(8) Å^3) and Z = 16 referring to $\text{Li}_{4.096(4)}$ Ge as one formula unit. The

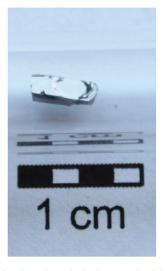


Fig. 1 Example of a bar-shaped single crystal of Li_{16.38}Ge₄ obtained from a melt Li₈₅Ge₁₅ at 530 °C.

Table 1 Fractional atomic coordinates and isotropic equivalent atomic displacement parameters for $\text{Li}_{17}\text{Ge}_4$ ($F\bar{4}3m$, Z=20, T=298 K, estimated standard deviations in parentheses)

Atom	Wyckoff position	x	у	z	$U_{\rm eq}/{\rm \mathring{A}}^2\cdot 10^3$
Ge1	16 <i>e</i>	0.159545(8)	х	x	13.03(4)
Ge2	16 <i>e</i>	0.916568(8)	\boldsymbol{x}	x	11.37(4)
Ge3	24f	0.32102(1)	0	0	13.27(5)
Ge4	24g	0.57015(1)	1/4	1/4	13.06(4)
Li1	16 <i>e</i>	0.0734(2)	x	x	31(1)
Li2	16 <i>e</i>	0.3031(2)	\boldsymbol{x}	x	21.6(8)
Li3	16 <i>e</i>	0.4175(2)	\boldsymbol{x}	x	22.3(9)
Li4	16 <i>e</i>	0.5575(2)	\boldsymbol{x}	x	23(1)
Li5	16 <i>e</i>	0.6877(2)	\boldsymbol{x}	x	28(1)
Li6	16 <i>e</i>	0.8314(2)	\boldsymbol{x}	x	27(1)
Li7	24f	0.1677(3)	0	0	25(1)
Li8	24g	0.0743(3)	1/4	1/4	23.1(9)
Li9	48h	0.0913(2)	x	0.2624(2)	32.0(9)
Li10	48h	0.0896(2)	\boldsymbol{x}	0.7612(2)	31.1(8)
Li11	48h	0.1547(1)	\boldsymbol{x}	0.5205(2)	32.5(8)
Li12	48h	0.1637(1)	\boldsymbol{x}	0.0027(2)	22.5(8)
Li13	4a	0	0	0	17(2)

unit cell contains 10 Li and three Ge atom positions (Table 2) where Li4 and Li5 are disordered. A careful analysis of difference Fourier maps after assigning all Ge and nine Li atom positions (Li1-Li3 and Li5-Li10) revealed occupational disorder along the crystallographic a-axis like that reported for Li_{16.42}Si₄. ¹⁰ As can be seen in Fig. 2a and 2b, the difference Fourier maps showing the strand-like residual electron density with peak-maxima at Wyckoff positions 4c and 8g are almost identical for $\text{Li}_{16.42(1)}\text{Si}_4$ and $\text{Li}_{16.38(2)}\text{Ge}_4$. Applying the disorder model as reported for Li_{16.42(1)}Si₄, ¹⁰ we subsequently obtained a very similar occupancy ratio of 0.616(8)/0.384(8) for Li4A on 4c(1/2, y, 1/4) and Li4B on 8g(x, y, 1/4), respectively, compared with 0.575(3)/0.425(3) found in Li_{16.42(1)}Si₄. Analogously to $\text{Li}_{16.42(1)}\text{Si}_4$, a split position for Li5 on 8f(0, x, y) was introduced. The split fractions converged to 0.75(4) for Li5A and 0.25(4) for Li5B (0.848(7)/0.152(7) in Li_{16,42(1)}Si₄;¹⁰ refinement

Table 2 Fractional atomic coordinates and isotropic equivalent atomic displacement parameters for Li_{4.096(4)}Ge (*Cmcm, Z* = 16, T = 100 K, estimated standard deviations in parentheses)

Atom	Wyckoff position	x	у	z	s.o.f.	$U_{\rm eq.}/$ $\mathring{\rm A}^2 \cdot 10^3$
Ge1	4 <i>c</i>	0	0.256372(6)	1/4	1	7.83(3)
Ge2	4c	1/2	0.454314(5)	1/4	1	6.35(3)
Ge3	8 <i>f</i>	1/2	0.105220(4)	0.067609(6)	1	6.83(2)
Li1	4 <i>c</i>	1/2	0.0333(1)	1/4	1	14.4(4)
Li2	4 <i>c</i>	1/2	0.3297(1)	1/4	1	13.5(4)
Li3	4c	0	0.3922(1)	1/4	1	17.5(5)
Li4A	4c	1/2	0.1476(2)	1/4	0.616(8)	52(3)
Li4B	8 <i>g</i>	0.210(1)	0.1385(2)	1/4	0.384(8)	21(2)
Li5A	8 <i>f</i>	0	0.1741(3)	0.0842(7)	0.75(4)	14(1)
Li5B	8 <i>f</i>	0	0.164(1)	0.123(4)	0.25(4)	24(6)
Li6	8 <i>f</i>	0	0.04650(7)	0.1225(1)	1	13.9(3)
Li7	8 <i>f</i>	0	0.31636(9)	0.0788(1)	1	16.5(3)
Li8	8 <i>f</i>	0	0.47089(9)	0.0908(1)	1	18.7(3)
Li9	8 <i>f</i>	1/2	0.23155(8)	0.1356(1)	1	19.1(3)
Li10	8 <i>f</i>	1/2	0.40425(8)	0.0639(1)	1	14.5(3)

details and the geometric relevance of the atom split are given in the ESI†). In case of atoms being uninvolved in disorder, site occupancy factors were refined to values close to full occupancy and therefore those positions were constrained to full occupancy. Thus, the unit cell contains 65.54(7) Li atoms as a consequence of the disorder (65.70(3) in $\operatorname{Li}_{16.42(1)}\operatorname{Si}_4^{10}$) and 16 Ge atoms, resulting in a crystallographic density of 2.011 g cm⁻³. The structure was finally solved with reliability factors of $R_1 = 0.023$ and w $R_2 = 0.027$ for all data (Table 6). $\operatorname{Li}_{16.38(2)}\operatorname{Ge}_4$ crystallizes isotypically with $\operatorname{Li}_{16.42(1)}\operatorname{Si}_4^{10}$

Structure description of Li₁₇Ge₄ and Li_{16,38}Ge₄

In our previous work we reported on the structures of $\text{Li}_{17}\text{Si}_4$ and $\text{Li}_{16.42}\text{Si}_4$ in detail. ^{9,10} Both phases were comparatively highlighted on the basis of SiLi_n coordination polyhedra and the disorder in $\text{Li}_{16.42}\text{Si}_4$ was illustrated with various structure models. Hence, we analogously elaborate on the structures of the isotypic phases $\text{Li}_{17}\text{Ge}_4$ and $\text{Li}_{16.38}\text{Ge}_4$ herein.

The structure of Li₁₇Ge₄ is closely related to the previously reported phase Li₂₁Ge₅²⁴ (Li_{16.8}Ge₄) only differing in the occupation of one fourfold special position. In detail, their common space group $F\bar{4}3m$ possesses four positions with site symmetry $\bar{4}3m$ (4a-d). Whereas Wyckoff positions 4a-d were claimed to be void in $Li_{21}Ge_5$, we found a fully occupied 4a site in Li₁₇Ge₄ with short but reasonable next nearest neighbor distances of 2.397(7) Å for Li1-Li13 (cf. Fig. 3 and Table 4). We note that since Li₂₂Si₅^{27,45} (its composition corresponds to a full occupancy of sites 4a-d) was revised to $\text{Li}_{21}\text{Si}_{5}$, 46 heavier analogues such as Li₂₂Ge₅ were supposed to crystallize with the Li₂₁Si₅ structure type as well (Li₂₁Ge₅).²⁴ We have already shown by computational methods that the fully relaxed structures of Li₁₇Si₄ and Li₂₁Si₅ decisively differ regarding the coordination environment around the 4a site. If this position is unoccupied, the first coordination shell, which is a (Li1)₄ tetrahedron (cf. Fig. 3), is markedly contracted, which was not observed in experimental data of Li₂₁Si₅ (Table S5 in the ESI†). Therefore it could be concluded that Li might have been overseen in the previous structure refinement (most likely a partial occupancy). Turning to Li₁₇Ge₄, the positional parameters are almost identical with Li₁₇Si₄ (Table S6 in the ESI†) and therefore an equal conclusion is reasonable.

In 2001, Goward $et\ al.^{18}$ have already reported on the revision of $\mathrm{Li}_{22}\mathrm{M}_5$ to $\mathrm{Li}_{17}\mathrm{M}_4$ (M = Ge, Sn, Pb). However, their model for " $\mathrm{Li}_{17}\mathrm{Ge}_4$ " involved partially occupied Li sites (Table 3), namely Li1A on $16e\ (3/4\ \mathrm{occ.})$, Li1B on $16e\ (1/4\ \mathrm{occ.})$, and Li13 on $4a\ (3/4\ \mathrm{occ.})$ resulting in the composition $\mathrm{Li}_{16.95}\mathrm{Ge}_4$ (note that for a better comparability the fractional atomic coordinates and labels were adapted to $\mathrm{Li}_{17}\mathrm{Ge}_4$). In the case of a void 4a site, the surrounding (Li1A)₄ tetrahedron (comparable with Li1 in Fig. 3) is slightly contracted to (Li1B)₄ whose vertices are markedly closer to the $4a\ \mathrm{center}\ (2.52\ \text{Å}\ \nu\mathrm{s}.$ $1.91\ \text{Å}).^{18}$ Interestingly, this scenario is in close agreement with the computationally relaxed structure of $\mathrm{Li}_{21}\mathrm{Si}_5^{\ 9}$ (Table S7 in the ESI†) where all fourfold positions are void. Consequently, a partial occupancy of the $4a\ \mathrm{position}$ as reported for $\mathrm{Li}_{16.95}\mathrm{Ge}_4$ and hence the existence of a small homogeneity

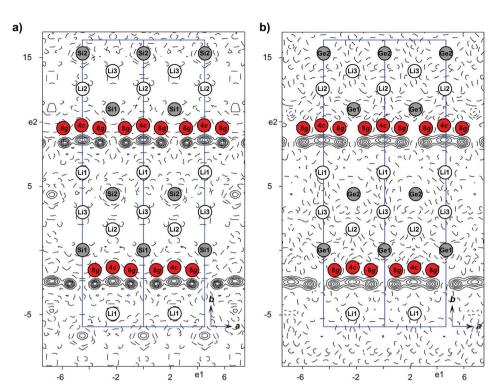


Fig. 2 Difference Fourier map $(F_o - F_c)$ shown for the layer defined by Tt1, Tt2 and Li2 in (a) Li_{16.42}Si₄¹⁰ and (b) Li_{16.38}Ge₄ (parallel to the *ab*-plane, calculated from single crystal data at 100 K and 123 K for Li_{16.42}Si₄ (contour lines ± 0.6 e Å⁻³) and Li_{16.38}Ge₄ (contour lines ± 0.5 e Å⁻³), respectively; cell edges are shown in blue).

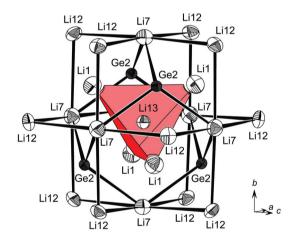


Fig. 3 Coordination environment of Li13 on the Wyckoff position 4a (Ge = black; Li = white; thermal ellipsoids at 70% probability, single crystal data at room temperature). The 1st, 2nd, 3rd, and 4th coordination shell is formed by a (Li1)₄ and (Ge2)₄ tetrahedron as well as a (Li7)₆ octahedron and a (Li12)₁₂ cuboctahedron.

region $\mathrm{Li}_{17-x}\mathrm{Tt}_4$ (0 < x < 0.2) are indeed meaningful. More recently, Lacroix-Orio $et~al.^{47}$ presented a Zn-doped derivative of the $\mathrm{Li}_{17}\mathrm{Ge}_4$ compound. They could not find any evidence for partially occupied Li positions and instead found small concentrations of Zn being incorporated at the 4a position ($\mathrm{Li}_{17-\varepsilon}\mathrm{Zn}_\varepsilon\mathrm{Ge}_4$, $\varepsilon=0.005(1)$).

Concluding, the fractional atomic coordinates of all $\rm Li_{17}Ge_4$ related phases listed in Table 3 are very similar and the scen-

ario of an unoccupied 4a position in $\text{Li}_{16.95}\text{Ge}_4$ fits the calculated data of the corresponding $\text{Li}_{21}\text{Si}_5$ structure very well. This strengthens the existence of a homogeneity region $\text{Li}_{17-x}\text{Tt}_4$ (0 < x < 0.2) which is deduced from the flexibility of the (Li1)₄(Tt₂)₄ tetrahedral star around the Wyckoff position 4a.⁹ Accordingly, the herein reported phase $\text{Li}_{17}\text{Ge}_4$ is regarded as the lithium-richest representative in the Li–Ge system.

The structure of $\rm Li_{17}Ge_4$ is closely related to a 6 × 6 × 6 superstructure of the body centered cubic (bcc) structure. As already shown by von Schnering and Nesper, it can be easily interpreted by 26 atom clusters ($\rm M_{26}$ with $\rm M=Tt$, Li) centered at the special positions $\rm 4\it a-d$ whereas $\rm Ge_4$ tetrahedra and $\rm Ge_6$ octahedra (note that $\rm Ge$ atoms are isolated by distances larger than 4.44 Å) are situated around $\rm 4\it a$, 4 $\rm c$ and 4 $\rm b$, 4 $\rm d$, respectively, corresponding to the arrangement of Na and Tl atoms in the NaTl structure.

Yet another possible way of looking at the structure of Li₁₇Ge₄ is the comparison of GeLi_n coordination polyhedra and their arrangement in the unit cell. This has proven to be a neat method for the comparison of lithium-rich Li–Si phases solely bearing isolated Si atoms in their structures (Li₁₇Tt₄, Li_{16.4}Tt₄ and Li₁₅Tt₄). As shown in Fig. 4a, Ge1, Ge3 and Ge4 are 13-coordinated by Li atoms, whereas Ge2 attains a coordination number (CN) of 14. Corresponding to the first coordination shell of Ge atoms, Li–Ge distances range from 2.659(4) Å to 3.053(3) Å (Table 4). The second Li shell is clearly separated with distances larger than 4.2564(3) Å. Interestingly, the polyhedra around Wyckoff positions 4a, 4c and 4b, 4d either form

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Table 3 Comparison of fractional atomic coordinates for $\text{Li}_{17}\text{Ge}_4$, $\text{Li}_{17-r}\text{Zn}_r\text{Ge}_4$, and $\text{Li}_{16.95}\text{Ge}_4$ (space group $F\bar{4}3$ m (for all phases), Z=20, estimated standard deviations in parentheses). Listed are x values for the special positions 16e (x, x, x), 24f (x, 0, 0), 24g (x, 1/4, 1/4) and x, z pairs for 48h (x, x, z)

At.	Wyck. pos.	$\mathrm{Li}_{17}\mathrm{Ge}_4$	$\mathrm{Li}_{17-e}\mathrm{Zn}_{e}\mathrm{Ge_{4}}^{47}$	${\rm Li}_{16.95}{\rm Ge_4}^{18}$	At.	Wyck. pos.	$\mathrm{Li}_{17}\mathrm{Ge}_4$	$\mathrm{Li}_{17-\varepsilon}\mathrm{Zn}_{\varepsilon}\mathrm{Ge_{4}}^{47}$	${\rm Li}_{16.95}{\rm Ge_4}^{18}$
Ge1	16 <i>e</i>	0.15955(1)	0.15958(2)	0.15952(5)	Li8	24 <i>g</i>	0.0743(3)	0.0740(6)	0.075(1)
Ge2	16 <i>e</i>	0.91657(1)	0.91667(3)	0.91684(5)	Li9	48h	0.0913(2)	0.0906(3)	0.0907(7)
Ge3	24f	0.32102(1)	0.32118(4)	0.32112(7)			0.2624(2)	0.2631(4)	0.2660(8)
Ge4	24g	0.57015(1)	0.57020(4)	0.56965(7)	Li10	48h	0.0896(2)	0.0904(4)	0.0914(7)
Li1A	16 <i>e</i>	0.0734(2)	0.0747(6)	0.0775			0.7612(2)	0.7613(4)	0.7597(9)
Li1B	16 <i>e</i>	_ ``	_ ` ` `	0.0587	Li11	48h	0.1547(1)	0.1554(3)	0.1540(5)
Li2	16 <i>e</i>	0.3031(2)	0.3033(3)	0.3032(6)			0.5205(2)	0.5216(4)	0.5216(9)
Li3	16 <i>e</i>	0.4175(2)	0.4179(5)	0.4169(9)	Li12	48h	0.1637(1)	0.1632(3)	0.1625(5)
Li4	16 <i>e</i>	0.5575(2)	0.5584(4)	0.5579(6)			0.0027(2)	0.0025(5)	0.005(1)
Li5	16 <i>e</i>	0.6877(2)	0.6864(4)	0.6876(7)	Li13	4a	0	0	0
Li6	16 <i>e</i>	0.8314(2)	0.8331(4)	0.8329(7)	Zn1	4a	_	0	_
Li7	24f	0.1677(3)	0.1678(6)	0.170(1)					
	v		. ,	. ,					

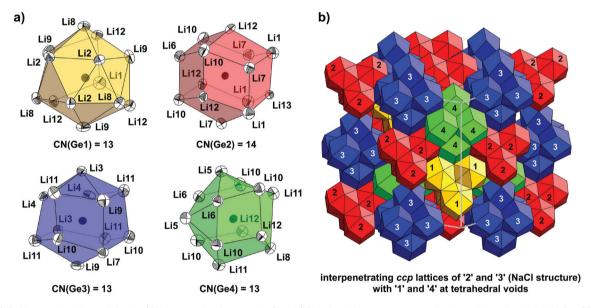


Fig. 4 (a) GeLin coordination polyhedra (CN = coordination number) and (b) their relative arrangement in the cubic unit cell of Li₁₇Ge₄ (Ge = black; Li = white; thermal ellipsoids at 70% probability, single crystal data at room temperature). Supratetrahedra and supraoctahedra are formed from Ge1Li₁₃, Ge2Li₁₄ and Ge3Li₁₃, Ge4Li₁₃ coordination polyhedra (denoted as 1, 2, 3 and 4).

supratetrahedra ([Ge1Li13]4 and [Ge2Li14]4 denoted as (1) and (2)) or supraoctahedra ([Ge3Li₁₃]₆ and [Ge4Li₁₃]₆ denoted as (3) and (4)), respectively (Fig. 4b). Accordingly, the structure of Li₁₇Ge₄ can be considered as two interpenetrating ccp lattices of (2) and (3), i.e. the NaCl structure, where tetrahedral voids are filled with (1) and (4).

Besides Li₁₇Ge₄ and Li₁₅Ge₄, Li_{16.38}Ge₄ is yet another representative exclusively bearing isolated Ge atoms. It is isotypic with Li_{16.42}Si₄¹⁰ which possesses a peculiar structure involving occupational and positional disorder along the crystallographic a-axes (cf. Fig. 2). A convenient way of illustrating the disordered structure of Li_{16.38}Ge₄ is the assumption of a simplified ordered model which has already been applied for the description and band structure calculations of Li_{16,42}Si₄.¹⁰ In detail, the atom positions Li4A, Li4B and Li5A (cf. Table 2) affected by disorder corresponding to the Wyckoff positions 4c

Table 4 Selected interatomic distances in $Li_{17}Ge_4$ (F43m, Z = 20, T = 298 K, estimated standard deviations in parentheses)

Atom pair			$d(\mathring{\mathrm{A}})$	d(Å) Atom pair			d(Å)		
Ge1	Li9	×3	2.659(4)	Ge3	Li10	×2	2.849(4)		
	Li1		2.813(7)		Li3	$\times 2$	2.855(2)		
	Li2	×3	2.884(1)		Li7		2.890(5)		
	Li8	×3	2.898(3)		Li11	$\times 4$	2.977(2)		
	Li12	×3	2.959(4)	Ge4	Li12	$\times 2$	2.680(3)		
Ge2	Li12	×3	2.686(3)		Li11	$\times 2$	2.709(3)		
	Li13		2.7244(3)		Li8		2.723(5)		
	Li7	×3	2.734(3)		Li5	$\times 2$	2.769(4)		
	Li6		2.780(6)		Li6	$\times 2$	2.856(2)		
	Li10	×3	2.933(4)		Li10	$\times 4$	3.053(3)		
	Li1	×3	2.969(4)	Li13	Li1	$\times 4$	2.397(7)		
Ge3	Li9	$\times 2$	2.673(4)		Ge2	$\times 4$	2.7244(3)		
	Li4	$\times 2$	2.760(3)		Li7	×6	3.162(5)		

(0.616(8) occ.), 8g (0.384(8) occ.) and 8f (0.75(4) occ.), respectively, are either regarded as half (Li4A, Li4B) or fully occupied (Li5A) resulting in the composition Li_{16.5}Ge₄. An accordingly ordered model with fully occupied atom positions and crystallographically independent sites for Li4B' and Li4B" (translate to Li4B in *Cmcm*) can be achieved by symmetry reduction and a cell enlargement (space group $P2_1/m$, a = 9.1016(4) Å, b = 13.2751(4) Å, c = 11.2744(4) Å, $\beta = 101.643(1)^\circ$; for crystallographic details, see ref. 10). The GeLi_n polyhedra occurring in the respective model "Li_{16.5}Ge₄" are depicted in Fig. 5a.

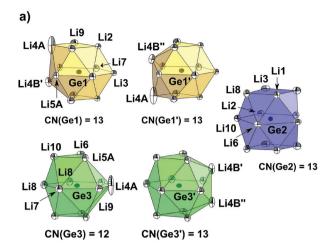
Similar to $\text{Li}_{17}\text{Ge}_4$, the first shell of Li atoms surrounding each Ge atom is clearly separated from the second one with distances between 2.596(2) Å to 3.309(3) Å and distances above 4.103(4) Å (Table 5). Whereas Ge1 and Ge2 are permanently 13-coordinated (Ge1Li₁₃/Ge1'Li₁₃ and Ge2Li₁₃ denoted as (1)/(1') and (2)), Ge3 attains coordination numbers of either 12 or 13 (Ge3Li₁₂ and Ge3'Li₁₃ denoted as (3) and (3')). The different coordination of Ge3 is attributed to the varying occupation of atom positions Li4A, Li4B' and Li4B". The arrangement of GeLi_n polyhedra in the unit cell of Li_{16.38}Ge₄ is achieved by stacking them into strands which proceed along the crystallographic *a*-axis (Fig. 5b). For the ordered model "Li_{16.5}Ge₄", the stacking sequence is indicated by numbers corresponding to various GeLi_n polyhedra highlighted in Fig. 5a.

Comparing the TtLi_n coordination polyhedra of all lithium-rich Li–Tt phases, which exclusively comprise isolated Tt atoms in their structures, the coordination numbers consistently increase from $\mathrm{CN}=12$ ($\mathrm{Li}_{15}\mathrm{Tt}_4$), over $\mathrm{CN}=12$ –13 ($\mathrm{Li}_{16.4}\mathrm{Tt}_4$) to $\mathrm{CN}=13$ –14 ($\mathrm{Li}_{17}\mathrm{Ge}_4$).

Solid solutions $\text{Li}_{17}\text{Si}_{4-x}\text{Ge}_x$ [x = 2.30(2), 3.08(4), 3.53(3)]

Li₁₇Si₄ and Li₁₇Ge₄ are isotypic phases that form solid solutions. Single crystalline samples of Li₁₇Si_{4-x}Ge_x were obtained from melt equilibration experiments and analyzed by single crystal and powder X-ray diffraction as well as energy dispersive X-ray spectroscopy. The Si-Ge ratios for Li₁₇Si_{4-x}Ge_x samples obtained from single crystal X-ray diffraction data were x = 2.30(2), 3.08(4), and 3.53(3). We note that these values deviate from the initial ones x = 1.0, 2.0, and 3.0 corresponding to the employed melts "Li₉₀Si_{7.5}Ge_{2.5}", "Li₉₀Si₅Ge₅" and "Li₉₀Si_{2.5}Ge_{7.5}" as the Si amount is reduced due to a partial reaction of Si with the stainless steel ampules; thus the Si-Ge ratios in the products are shifted toward higher Ge contents. As can be seen in Fig. 6, the cell axes and volumes (determined from PXRD patterns of the respective samples by Rietveld refinement, Fig. S2†) linearly increase with increasing Ge concentrations in Li₁₇Si_{4-x}Ge_x revealing a perfect behavior obeying Vegard's law.43 Additionally, results from EDX measurements agree well with the crystallographically determined Si-Ge ratios (impurities originating from the stainless steel ampule were not detected).

Analyzing the distribution of Si and Ge on atom positions Tt1–4, the Si–Ge ratios are very similar for Tt1, Tt3, and Tt4, whereas Tt2 on the Wyckoff position 16e~(x,~x,~x) features a slight preference for Si (Table S1–4†). Comparing the coordination environment of Tt2 and Tt1, Tt3, Tt4, the former is



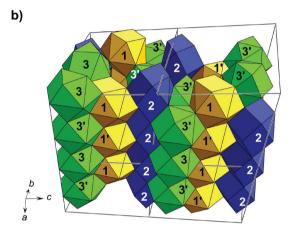


Fig. 5 (a) $GeLi_n$ coordination polyhedra occurring in an idealized model for $Li_{16.38}Ge_4$ with a composition of $Li_{16.5}Ge_4$ (space group $P2_1/m$, fully occupied and crystallographically independent atom positions Li4B', Li4B'' (both correspond to Li4B in $Li_{16.38}Ge_4$), Li4A, and Li5A); (b) stacking of $GeLi_n$ polyhedra by sharing opposite faces resulting in parallel rods which run along the crystallographic a-axis (Ge = black, Li = white, thermal ellipsoids at 90% probability, single crystal data at 100 K). The polyhedra stacking in the structure model " $Li_{16.5}Ge_4$ " is indicated by numbers X which correspond to the coordination polyhedra of atom GeX in (a).

Table 5 Selected interatomic distances in Li_{16.38}Ge₄ (*Cmcm*, Z = 16, T = 123 K, estimated standard deviations in parentheses)

Atom pair			d(Å)	Atom	pair	$d(\mathring{\mathrm{A}})$	
Ge1	Li7	×2	2.631(2)	Ge2	Li8	×4	3.127(1)
	Li5B	$\times 2$	2.64(2)	Ge3	Li4A		2.596(2)
	Li4B	$\times 2$	2.772(4)		Li7		2.603(2)
	Li9	$\times 4$	2.790(1)		Li8		2.693(2)
	Li2	$\times 2$	2.792(1)		Li6	$\times 2$	2.7188(9)
	Li5A	$\times 2$	2.854(8)		Li5B	$\times 2$	2.723(8)
	Li3		3.001(2)		Li5A	$\times 2$	2.747(3)
	Li4A	$\times 2$	3.309(3)		Li4B	$\times 2$	2.854(3)
Ge2	Li6	$\times 2$	2.647(2)		Li10	$\times 2$	2.875(1)
	Li3	$\times 2$	2.657(1)		Li1		2.896(1)
	Li10	$\times 2$	2.707(2)		Li9		2.932(2)
	Li2		2.753(2)		Li8		2.983(2)
	Li1	$\times 2$	2.867(2)				, ,

18.90 6750 Li₁₇Si_{4-x}Ge_x x = 4x = 3.53(3)6700 18.85 x = 2.30(2)6650 18.80 **V/Å**3 6600 18.75 ▲ Si-Ge ratio (EDX) Si-Ge ratio (single crystal data) 6550 18.70 20 40 60 100

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Fig. 6 Trend of cell volumes vs. Ge contents in $\text{Li}_1\text{2Si}_{4-x}\text{Ge}_x$ (x=0, 2.30(2), 3.08(4), 3.53(3), 4). Cell parameters were determined from respective PXRD patterns by Rietveld refinement (Fig. S2), and Ge contents were obtained from either single crystal X-ray diffraction data or EDX (error bars for *a*, *V*, and $x_{\text{single crystal}}$ (in at%) are smaller than data point icons).

(n(Ge)/[n(Si)+n(Ge)]) in at.% Ge

14- and the latter are 13-coordinated by Li atoms with similar Ge–Li distances (2.68 Å–2.95 Å νs . 2.65–3.04 Å). The phenomenon that different crystallographic sites are substituted differently is also known as the "coloring problem". ⁴⁸ In some cases the site preferences cannot be deduced on the basis of simple chemical reasoning (*e.g.* differences in electronegativities) and quantum chemical calculations may give a reasonable explanation. ⁴⁹ Here, the focus is set on experimental work and we note that small differences in the distribution of Si and Ge on atom positions Tt2 and Tt1, Tt3, Tt4 were traced.

Thermodynamic stability of Li₁₇Ge₄ and Li_{16.38}Ge₄

The Li–Ge phase diagram was determined by Federov & Molochka²³ in 1966 and later revised by Grüttner²⁵ in his dissertation. However, a current compilation of the Li–Ge system⁵⁰ did not include Grüttner's results and, hence, significant information is missing. Therefore and due to the recent improvements of the Li–Si phase diagram (>76 at% Li),⁸⁻¹⁰ a detailed redetermination of the respective portion of the Li–Ge system is essential.

The lithium-rich section of the Li–Ge phase diagram (>79 at % Li) was studied by DSC investigations of samples with systematically different compositions $\mathrm{Li_{17}Ge_4}$, " $\mathrm{Li_{16.5}Ge_4}$ " and " $\mathrm{Li_{16}Ge_4}$ ". Accordingly, PXRD patterns correspond to purephase $\mathrm{Li_{17}Ge_4}$, a mixture of $\mathrm{Li_{17}Ge_4}$ and $\mathrm{Li_{16.38}Ge_4}$, and a mixture of $\mathrm{Li_{16.38}Ge_4}$ and $\mathrm{Li_{16.38}Ge_4}$, respectively (Fig. 7).

The thermograms of these samples are depicted in Fig. 7. The first thermal events in these cooling traces (signal 1–3) are assigned to the crossing of the liquidus boundary. Analogously to the Li–Si system, 10 signals (4) and (5) at 520–522 °C and 627 °C are attributed to the peritectic formation temperatures of Li $_{17}$ Ge $_4$ (481–486 °C for Li $_{17}$ Si $_4$) and Li $_{16.38}$ Ge $_4$ (618 °C for Li $_{16.42}$ Si $_4$), respectively. This is additionally strengthened by our results from melt equilibration experiments (see above) where crystals of Li $_{16.38}$ Ge $_4$ are only afforded above temperatures of 520 °C. Note that signal (5) corresponding to the peri

tectic formation of Li $_{16.38}$ Ge $_4$ from melt and Li $_{15}$ Ge $_4$ is superimposed by signals (1) and (2) in the cooling traces of Li $_{17}$ Ge $_4$ and "Li $_{16.5}$ Ge $_4$ " (Fig. 7), respectively, but clearly visible for the "Li $_{16}$ Ge $_4$ " sample. Instead, it can be recognized at around 630 °C in the respective heating trace, exemplarily shown for Li $_{17}$ Ge $_4$ (effect 5'). Furthermore, long term annealing experiments of "Li $_{16}$ Ge $_4$ " samples (Fig. S1 in the ESI†) established Li $_{16.38}$ Ge $_4$ as a high-temperature phase being stable above ~400 °C until 627 °C, just like Li $_{16.42}$ Si $_4$ existing between 470 and 618 °C. ¹⁰ We note that the decomposition behavior of Li $_{16.38}$ Ge $_4$ is very sluggish and even harder to trace than in the case of its Si counterpart.

Finally, the recent results from DSC investigations are compiled in an updated Li–Ge phase diagram (Fig. 8b) which was revised from Grüttner's previously determined one shown in Fig. 8a. A comparison with the Li–Si phase diagram (Fig. 8c) reveals similarities to the Li–Ge system. An interesting difference is the stability of Li₁₅Tt₄. Whereas Li₁₅Si₄ is metastable and decomposes above \sim 170 °C, ⁸ Li₁₅Ge₄ is thermodynamically stable and melts congruently at 720 °C. ²⁵ Furthermore, uncertainties regarding the isotherms at 610 °C and 618 °C in the Li–Si phase diagram¹⁰ could not be found for the Li–Ge system.

Conclusion

The germanides Li₁₇Ge₄ and Li_{16.38}Ge₄ were established as further representatives of the Li-Ge system. The latter is assigned a high-temperature phase which exists between ~400 and 627 °C, the former, the lithium-richest Li-Ge phase, decomposes peritectically at 521 °C into melt and Li_{16.38}Ge₄. Li_{16.38}Ge₄ can be retained at room temperature if according melts are cooled to the respective temperature region and subsequently quenched. Both germanides are isotypic to the silicides Li₁₇Si₄ and Li_{16.42}Si₄ extending the family of isotypic lithium tetrelides to Li₁₇Tt₄, Li_{16.4}Tt₄, Li₁₅Tt₄, Li₁₄Tt₆, Li₁₂Tt₇, and LiTt (Tt = Si, Ge). The previously reported Li_{16.95}Ge₄ can be regarded as representative of a homogeneity region $\text{Li}_{17-x}\text{Tt}_4$ (0 < x < 0.2) with $\text{Li}_{17}\text{Ge}_4$ and $\text{Li}_{16.8}\text{Ge}_4$ ($\text{Li}_{21}\text{Ge}_5$) as border phases only differing in the occupation of the Wyckoff position 4a. Moreover, the validity of Vegard's law for the solid solutions Li₁₇Si_{4-x}Ge_x was confirmed and small differences in the distribution of Si and Ge to the four crystallographically independent atom positions were observed. Regarding the thermodynamic properties, the regions of stability for Li₁₇Tt₄ and Li_{16.42}Tt₄ are very similar. Interesting are also the thermodynamic and structural differences of lithium silicides and germanides. For instance, whereas Li₁₅Si₄ is a metastable phase, Li₁₅Ge₄ melts congruently at 720 °C. Further, the phases Li₉Ge₄ and Li₇Ge₁₂ are not known in the Li-Si system. In particular, the synthesis of a hypothetical phase Li₇Si₁₂ would be an intriguing field of research since it may serve as a precursor for a new allotrope of Si, just as was reported for Li₇Ge₁₂ and its mild oxidation to allo-Ge.^{36,51}

a) ■ Li₁₇Ge₄ Li₁₇Ge₄ -(1) 693 °C set ~670 °C 650 1) 657 °C (5') intensity 640 °C set ~630 °C) 550 (4) 4 522 °C 500-0.5 1.0 40 -1.02θ(°)-DSC / µVmg-1 b) Li_{4.10}Ge "Li_{16.5}Ge₄" 700 Li₁₇Ge₄ 2 663 °C intensity 600 **4**) 520 °C exo 500 30 1.0 DSC / μ Vmg $^{-1}$ — 2θ(°) → c) Li_{4.10}Ge "Li₁₆Ge₄" ● Li₁₅Ge₄ (3) 650 intensity 550

Fig. 7 PXRD patterns and corresponding DSC thermograms of bulk samples (a) $Li_{17}Ge_4$, (b) $Li_{16}Ge_4$, and (c) $Li_{16}Ge_4$ (PXRD patterns: experimental = black, $Li_{17}Ge_4$ (calc.) = yellow, $Li_{4.10}Ge$ (calc.) = blue, $Li_{15}Ge_4$ (calc.) = red; DSC thermograms: heating and cooling traces are shown in red and blue, respectively, a signal assignment is given in the Li-Ge phase diagram in Fig. 8b).

50

40

2θ(°) →

30

Experimental section

10

Synthesis

Starting materials were Li rods (99%, Rockwood-Lithium), Si powder (99.999%, Alfa Aesar) and Ge pieces (99.999%, Chempur). All steps of synthesis and sample preparation were carried out in a glove box (MBraun, Ar atmosphere, $\rm H_2O$ and $\rm O_2$ levels <0.1 ppm). Ta and stainless steel ampules were thoroughly cleaned, heated to 1000 °C (Ta) or 800 °C (stainless steel) under dynamic vacuum ($p < 1 \times 10^{-3}$ mbar) for at least 2 h and transferred to the glove box. An all-glass Schlenk line

supplied with Ar, which is dried over P_2O_5 , molecular sieve and heated titanium sponge (T = 750 °C), was used for heating and handling under inert conditions.

10 Kmin-1 cooling

1.5

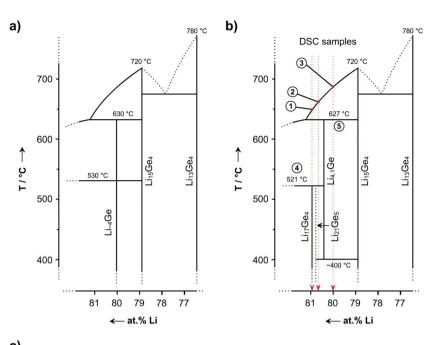
1.0

DSC / µVmg⁻¹ -

0.5

Large single crystals of $\rm Li_{17}Ge_4$ and $\rm Li_{4.10}Ge$ ($\rm Li_{16.38}Ge_4$) (cf. Fig. 1) were obtained from equilibrating melts with compositions " $\rm Li_{95}Ge_5$ " and " $\rm Li_{85}Ge_{15}$ " at temperatures of 400 and 530 °C in Ta ampules (slow cooling from 700 °C at a rate of 5 K h⁻¹ followed by 48 hours dwelling at specified temperatures) and subsequent isothermal melt-centrifugation. Details of this procedure have already been described in ref. 9 and 52. Crystals of $\rm Li_{17}Si_{4-x}Ge_x$ [x=0, 2.30(2), 3.08(4), 3.53(3)] were

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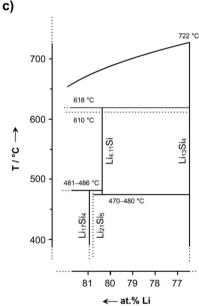


Fig. 8 (a) Excerpt of the Li–Ge phase diagram as reported from Grüttner²⁵ (the composition of the eutectic between Li₁₅Ge₄ and Li₁₃Ge₄ was not determined), (b) its revision based on DSC investigations and annealing experiments of "Li₁₆Ge₄" samples reported herein, and (c) the most recent Li–Si phase diagram for Li concentrations >76%.¹⁰

grown analogously in stainless steel ampules from melts with compositions "Li $_{90}$ Si $_{10}$ ", "Li $_{90}$ Si $_{7.5}$ Ge $_{2.5}$ ", "Li $_{90}$ Si $_{5}$ Ge $_{5}$ " and "Li $_{90}$ Si $_{2.5}$ Ge $_{7.5}$ " equilibrated at 450 °C.

Furthermore, elemental mixtures with compositions $\mathrm{Li}_{17}\mathrm{Ge}_4$, " $\mathrm{Li}_{16.5}\mathrm{Ge}_4$ " and " $\mathrm{Li}_{16}\mathrm{Ge}_4$ " with a total amount of 2.5 g each were loaded into Ta ampules which were sealed by arc welding inside the glove box. For achieving targeted compositions with sufficient precision, a batch size of 2.5 g was deemed appropriate to keep weighing errors minimal. 9,10 Subsequently, ampules were sealed in silica jackets under vacuum and annealed in a muffle furnace. The temperature was raised

to 750 °C at a rate of 10 K min $^{-1}$ and held for 0.5 h followed by cooling to 500–550 °C at a rate of 10 K min $^{-1}$. After a dwell time of one hour, ampules were quenched in water and transferred back to the glove box. Obtained products were ground in agate mortars and characterized by powder X-ray diffraction (cf. Fig. 7).

Differential scanning calorimetry (DSC)

Differential scanning calorimetry was carried out with a Netzsch DSC 404 Pegasus apparatus. Cylindrical Nb crucibles (L = 15.0 mm, OD = 6.5 mm, ID = 5.0 mm) were thoroughly

cleaned, heated to 1000 °C under dynamic vacuum ($p < 1 \times 1$ 10⁻³ mbar) for 2 h and transferred to an Ar-filled glove box. Crucibles were loaded with 30-50 mg of the sample (Li₁₇Ge₄, "Li_{16.5}Ge₄" and "Li₁₆Ge₄"). Subsequently, the open end was roughly closed by crimping and then sealed by arc-welding inside the glove box under cooling. A sealed Nb crucible without the sample served as a reference. For all measurements an Ar-flow of 60-70 mL min⁻¹ and a heating/cooling rate of 10 K min⁻¹ were used. Samples were recovered after the measurement inside an Ar-filled glove box. Data were handled with the program Proteus Thermal Analysis.⁵³

Annealing experiments

In order to further investigate the thermodynamic stability of Li_{4.10}Ge (Li_{16.38}Ge₄), batches of 100-150 mg of "Li₁₆Ge₄" bulk material were sealed in Ta ampules and annealed in a muffle furnace at 200, 400 and 510 °C (10 K min⁻¹ heating rate) for three days. Thereafter, ampules were quenched in water and transferred inside an Ar-filled glove box. Products were ground in agate mortars and subsequently characterized by powder X-ray diffraction (Fig. S1†).

Single crystal X-ray diffraction and structure determination

Crystals of Li₁₇Ge₄ and Li_{4.096(4)}Ge (Li_{16.38(2)}Ge₄) were handled in an Ar-filled glove box, selected under a microscope and sealed inside glass capillaries. For the best specimen, intensity data were collected at room temperature (Li₁₇Ge₄) and 123 K (Li_{16.38(2)}Ge₄) on a Bruker X-ray diffractometer equipped with a CCD detector (Apex II, κ-CCD), a fine-focused sealed tube with MoK_{α} radiation ($\lambda = 0.71073$ Å) and a graphite monochromator using the Bruker Apex2 software.⁵⁴ Integration, data reduction and absorption correction were done using SAINT and SADABS. 55,56 The space groups $F\bar{4}3m$ (Li₁₇Ge₄) and Cmcm (Li_{16.38(2)}Ge₄) were assigned on the basis of the systematic absence and the statistical analysis of the intensity distributions. For Li₁₇Ge₄, Friedel pairs were not merged since the assigned space group is non-centrosymmetric. The Flack⁵⁷ parameter was determined as 0.50(3). The structures were solved by direct methods (Shelxs-97⁵⁸) and refined with full-matrix least squares on F2 (Shelxl-9759). Difference Fourier maps $F_{\rm o} - F_{\rm c}$ were calculated with Jana2006.⁶⁰ All refinement results are compiled in Table 6.

Details of the single crystal X-ray structure determination, refinement data, fractional atomic coordinates and isotropic equivalent atomic displacement parameters for $\text{Li}_{17}\text{Si}_{4-x}\text{Ge}_x$ [(x = 2.30(2), 3.08(4), 3.53(3)] are given in Table S1-4 in the ESI.† Further data may be obtained from Fachinformationszentrum Karlsruhe, D-76344 Eggenstein-Leopoldshafen, Germany (fax: (+49)7247-808-666; e-mail: crysdata@fiz-karlsruhe.de) on quoting the depository numbers CSD-427231 ($Li_{4.10}$ Ge ($Li_{16.38}$ Ge₄)), CSD-427232 (Li₁₇Ge₄), CSD-427233 (Li₁₇Si_{0.47}Ge_{3.53}), CSD-427234 $(Li_{17}Si_{0.92}Ge_{3.08})$, and CSD-427235 $(Li_{17}Si_{1.70}Ge_{2.30})$.

Powder X-ray diffraction (PXRD)

PXRD patterns were recorded on a Stoe Stadi P diffractometer (Ge(111) monochromator for Cu $K_{\alpha 1}$ radiation, $\lambda = 1.54056 \text{ Å}$)

Table 6 Crystallographic data and structure refinement for Li₁₇Ge₄ and Li_{4.096(4)}Ge

Empirical formula T/K Formula weight/g·mol ⁻¹ Crystal size/mm ³ Crystal color Crystal shape Space group Structure type	$\begin{array}{l} {\rm Li_{17}Ge_4} \\ 298(2) \\ 408.34 \\ 0.40 \times 0.40 \times 0.35 \\ {\rm Metallic\ silver} \\ {\rm Block} \\ F\bar{4}3m \\ {\rm Li_{17}Pb_4} \end{array}$	$\text{Li}_{4.096(4)}\text{Ge}$ 123(2) 101.01 0.37 × 0.24 × 0.23 Metallic silver Bar Cmcm $\text{Li}_{4.11}\text{Si}$
Unit cell dimension/Å	a = 18.8521(3)	a = 4.5511(2) b = 22.0862(7) c = 13.2751(4)
$V/\text{Å}^3$	6700.1(2)	1334.37(8)
Z	20	16
ρ (calc.)/g cm ⁻³	2.024	2.011
μ/mm^{-1}	8.832	8.860
F(000)	3580	709
θ Range/ $^{\circ}$	1.87-45.26	1.84-40.25
Index range <i>hkl</i>	$-37 \le h \le +23$	$-6 \le h \le +8$
	$-37 \le k \le +30$	$-32 \le k \le +40$
	$-37 \le l \le +37$	$-24 \le l \le +19$
Reflections collected	67 542	15 241
Independent reflections	$2757 (R_{int} =$	2369 ($R_{\rm int} =$
	0.047)	0.023)
Reflections with $I > 2\sigma(I)$	$2547 (R_{\sigma} = 0.017)$	$1920 (R_{\sigma} = 0.017)$
Data/restraints/parameter	2757/0/68	2369/0/82
Absorption correction	Multi-scan	Multi-scan
Goodness-of-fit on F^2	1.106	1.042
Final <i>R</i> indices $[I > 2\sigma(I)]^{a,b}$	$R_1 = 0.018$	$R_1 = 0.015$
a h	$wR_2 = 0.037$	$wR_2 = 0.026$
<i>R</i> indices (all data) ^{<i>a,b</i>}	$R_1 = 0.022$	$R_1 = 0.023$
	$wR_2 = 0.038$	$WR_2 = 0.027$
Extinction coefficient	$1.59(9) \times 10^{-4}$	$1.52(7) \times 10^{-3}$
Flack parameter	0.50(3)	-
Largest diff. peak and hole/e Å ⁻³	0.46 and -0.69	0.69 and -0.52

 ${}^{a}R_{1} = \sum ||F_{0}| - |F_{c}|| / \sum |F_{0}|. {}^{b}WR_{2} = \left[\sum w(F_{0}^{2} - F_{c}^{2})^{2} / \sum w(F_{0}^{2})^{2}\right]^{1/2}.$

equipped with a Dectris Mythen DCS 1 K solid state detector. Investigated samples were (i) single crystals of $Li_{17}Si_{4-x}Ge_x$ (x =0, 2.30(2), 3.08(4), 3.53(3), 4), (ii) bulk samples of Li₁₇Ge₄, "Li_{16.5}Ge₄" and "Li₁₆Ge₄", and (iii) samples of "Li₁₆Ge₄" annealed at different temperatures. These were thoroughly ground in agate mortars, sealed inside 0.3 mm glass capillaries and measured in a 2θ -range of 5–90° (PSD steps: 0.06-1.00°; time per step: 20-40 s).

Energy dispersive X-ray spectroscopy (EDX)

A Jeol-JSM 7500F scanning electron microscope equipped with an Oxford X-Max EDX analyzer with Mn as an internal standard was used for determining the Si-Ge ratios in Li₁₇Si_{4-x}Ge_x [x = 2.30(2), 3.08(4), 3.53(3)]. Samples were handled inside an Ar-filled glove box and fixed on a graphite platelet which was mounted on an aluminum stub.

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